

30A, 200V Ultrafast Diode

The RURP3020 is an ultrafast diode ($t_{rr} < 45\text{ns}$) with soft recovery characteristics. It has a low forward voltage drop and is of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

This device is intended for use as an energy steering/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristics minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

Formally development type TA09645.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURP3020	TO-220AC	RURP3020

NOTE: When ordering, use the entire part number.

Symbol



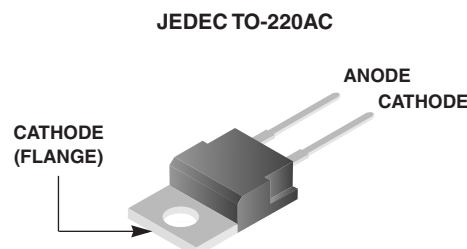
Features

- Ultrafast with Soft Recovery <45ns
- Operating Temperature 175°C
- Reverse Voltage 200V
- Avalanche Energy Rated

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Packaging



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

	RURP3020	UNITS
Peak Repetitive Reverse Voltage V_{RRM}	200	V
Working Peak Reverse Voltage V_{RWM}	200	V
DC Blocking Voltage V_R	200	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_C = 145^\circ\text{C}$)	30	A
Repetitive Peak Surge Current I_{FRM} (Square Wave 20kHz)	70	A
Nonrepetitive Peak Surge Current I_{FSM} (Halfwave 1 Phase 60Hz)	325	A
Maximum Power Dissipation P_D	125	W
Avalanche Energy (See Figures 7 and 8) E_{AVL}	20	mJ
Operating and Storage Temperature T_{STG}, T_J	-55 to 175	°C

Electrical Specifications

$T_C = 25^\circ\text{C}$, Unless Otherwise Specified.

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V_F	$I_F = 30\text{A}$	-	-	1.0	V
	$I_F = 30\text{A}, T_C = 150^\circ\text{C}$	-	-	0.85	V
I_R	$V_R = 200\text{V}$	-	-	250	μA
	$V_R = 200\text{V}, T_C = 150^\circ\text{C}$	-	-	1.0	mA
t_{rr}	$I_F = 1\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	45	ns
	$I_F = 30\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	50	ns
t_a	$I_F = 30\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	20	-	ns
t_b	$I_F = 30\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	15	-	ns
$R_{\theta JC}$		-	-	1.2	$^\circ\text{C}/\text{W}$

DEFINITIONS

V_F = Instantaneous forward voltage ($p_w = 300\mu\text{s}$, $D = 2\%$).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 6), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 6).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

$R_{\theta JC}$ = Thermal resistance junction to case.

p_w = pulse width.

D = duty cycle.

Typical Performance Curves

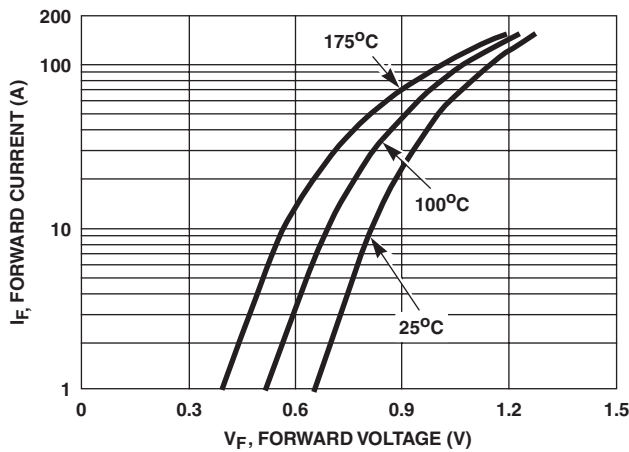


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

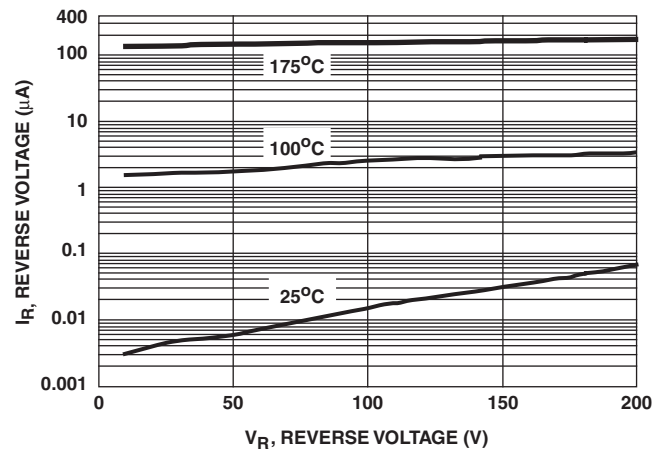


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

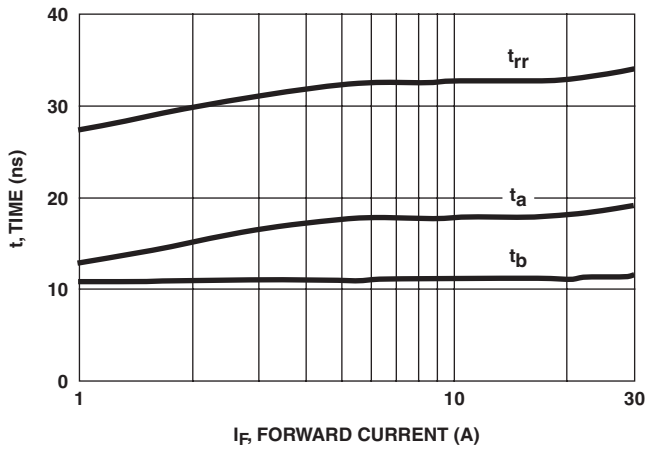


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

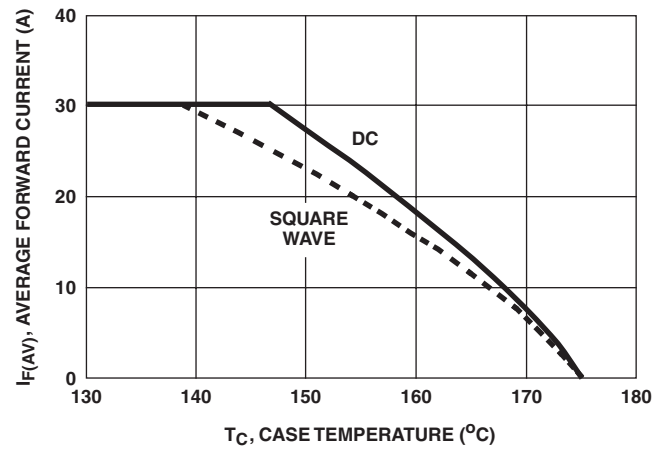


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

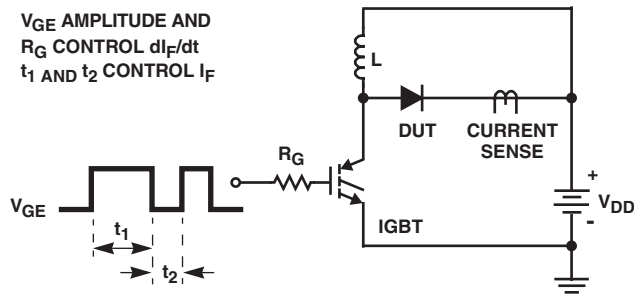


FIGURE 5. t_{rr} TEST CIRCUIT

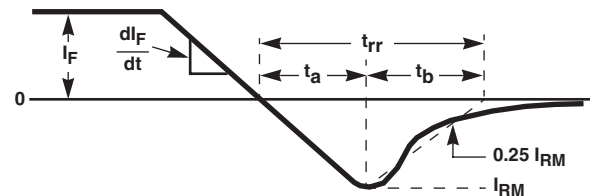


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

$I = 1A$
 $L = 40mH$
 $R < 0.1\Omega$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

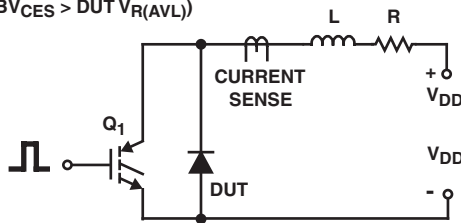


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

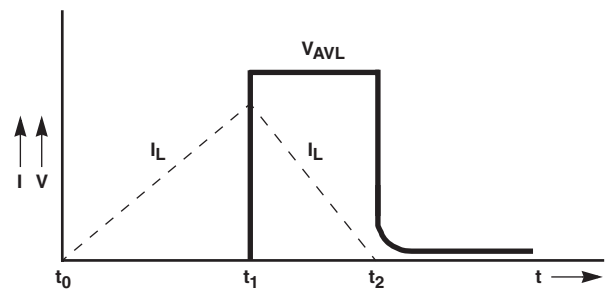


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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